Silicon Switching Diode

Features

• These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

ON

ON Semiconductor®

http://onsemi.com

o 1

ANODE

30-

CATHODE



Rating	Symbol	Max	Unit
Continuous Reverse Voltage	V _R	80	V
Recurrent Peak Forward Current	١ _F	200	mA
Peak Forward Surge Current Pulse Width = 10 μ s	I _{FM(surge)}	500	mA

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation, FR-4 Board (Note 1) T _A = 25°C	PD	225	mW
Derated above 25°C		1.8	mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	555	°C/W
Total Device Dissipation, FR-4 Board (Note 2) $T_A = 25^{\circ}C$	P _D	360	mW
Derated above 25°C		2.9	mW/°C
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	345	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-4 @ Minimum Pad

2. FR-4 @ 1.0×1.0 Inch Pad



SOT-416 / SC-75 CASE 463 STYLE 2

MARKING DIAGRAM



*Date Code orientation and/or orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
DA121TT1G	SOT-416 (Pb-Free)	3000 / Tape & Reel

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
Forward Voltage -	V _F			mV
(I _F = 1.0 mA)		-	715	
(I _F = 10 mA)		-	866	
(I _F = 50 mA)		-	1000	
(I _F = 150 mA)		-	1250	
Reverse Current -	I _R			μA
(V _R = 75 V)		-	1.0	
(V _R = 75 V, T _J = 150°C)		-	50	
(V _R = 25 V, T _J = 150°C)		-	30	
Capacitance - (V _R = 0, f = 1.0 MHz)	CD	-	2.0	pF
Reverse Recovery Time - ($I_F = I_R = 10$ mA, $R_L = 50 \Omega$) (Figure 1)	t _{rr}	-	6.0	ns
Stored Charge - (I _F = 10 mA to V _R = 6.0 V, R _L = 500 Ω) (Figure 2)	QS	-	45	PC
Forward Recovery Voltage – (I_F = 10 mA, t_r = 20 ns) (Figure 3)	V _{FR}	-	1.75	V







Figure 2. Recovery Charge Equivalent Test Circuit











PACKAGE DIMENSIONS

SC-75 (SOT-416) CASE 463-01 **ISSUE F**





NOTES: DIMENSIONING AND TOLERANCING PER ANSI 1. Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.

2.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.70	0.80	0.90	0.027	0.031	0.035
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.15	0.20	0.30	0.006	0.008	0.012
С	0.10	0.15	0.25	0.004	0.006	0.010
D	1.55	1.60	1.65	0.059	0.063	0.067
E	0.70	0.80	0.90	0.027	0.031	0.035
е	1.00 BSC			0.04 BSC		
L	0.10	0.15	0.20	0.004	0.006	0.008
HE	1.50	1.60	1.70	0.061	0.063	0.065

STYLE 2: PIN 1. ANODE 2. N/C

3. CATHODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and 💷 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your loca Sales Representative